



DMG2302UKQ

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	90mΩ @ V _{GS} = 4.5V	2.8A
20V	120mΩ @ V _{GS} = 2.5V	2.4A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters
- Motor Control





Top View

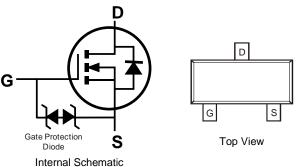


Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



Ordering Information (Note 5)

Part Number	Case	Packaging
DMG2302UKQ-7	SOT23	3,000/Tape & Reel
DMG2302UKQ-13	SOT23	10,000/Tape & Reel

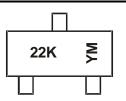
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



22K = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Date Code Hoy												
Year	2015		2016	2017		2018	2019		2020	2021		2022
Code	С		D	E		F	G		Н			J
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	20	V	
Gate-Source Voltage	V _{GSS}	±12	V		
Continuous Drain Current (Note 7) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	2.8 2.2	А
Maximum Continuous Body Diode Forward Curre	ent (Note 7)	Is	1.1	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle =	1%)	I _{DM}	12	А	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	0.66	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	192	°C/W
Total Power Dissipation (Note 7)	·	PD	1.1	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	R _{0JA}	115	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)			71			
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}	_		10	μA	$V_{DS} = 16V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	—	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						·
Gate Threshold Voltage	V _{GS(TH)}	0.3	0.6	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance			61	90	mΩ	$V_{GS} = 4.5V, I_D = 3.6A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	80	120	11152	V _{GS} = 2.5V, I _D = 3.1A
Diode Forward Voltage	V_{SD}	—	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.0A$
DYNAMIC CHARACTERISTICS (Note 9)			-			
Input Capacitance	Ciss	—	130		pF	
Output Capacitance	Coss	—	26	_	pF	[−] V _{DS} = 10V, V _{GS} = 0V −f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	18	—	pF	1 - 1.00012
Gate Resistance	Rg	—	2.7	—	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	1.4	_	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	2.8	_	nC	
Gate-Source Charge	Q _{gs}	_	0.1		nC	$V_{DS} = 10V, I_D = 3.6A$
Gate-Drain Charge	Q _{gd}	_	0.5	_	nC	7
Turn-On Delay Time	t _{D(ON)}	—	0.6	—	ns	
Turn-On Rise Time	t _R	—	2.7	—	ns	$V_{DS} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t _{D(OFF)}	_	4.2	—	ns	$R_g = 1\Omega, R_L = 2.78\Omega$
Turn-Off Fall Time	t _F	_	1.7	_	ns	<u>] </u>
Reverse Recovery Time	t _{RR}	_	5.3	_	ns	I _F = 3.6A, di/dt = 100A/µs
Reverse Recovery Charge	Q _{RR}	—	0.5		nC	I _F = 3.6A, di/dt = 100A/µs

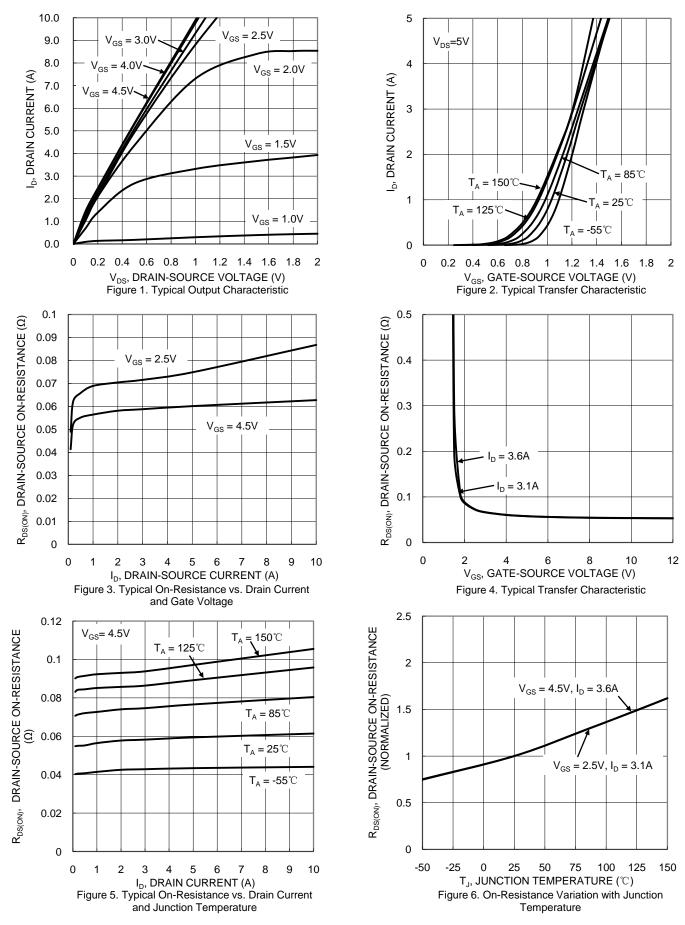
6. Device mounted on FR-4 PCB with minimum recommended pad layout. Notes:

Device mounted on 1" x 1" FR-4 PCB with high-coverage 2oz copper, single sided.
 Short duration pulse test used to minimize self-heating effect.

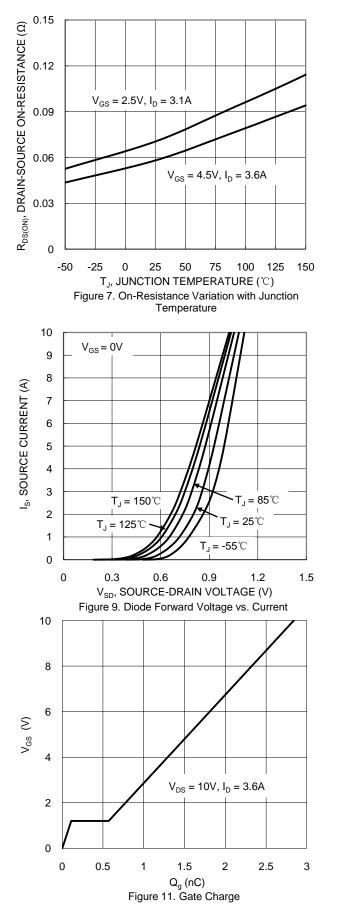
9. Guaranteed by design. Not subject to product testing.

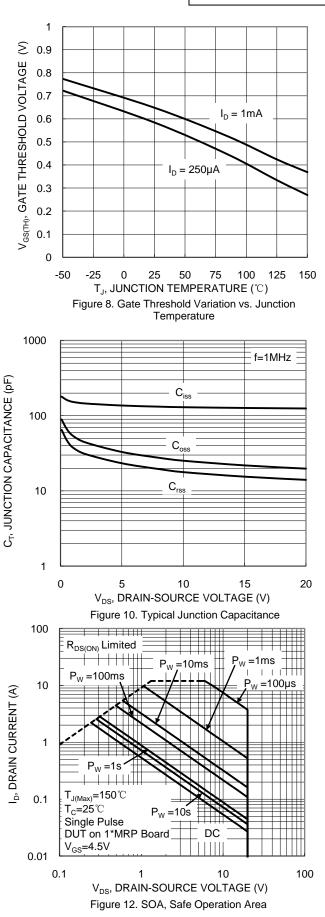


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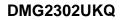




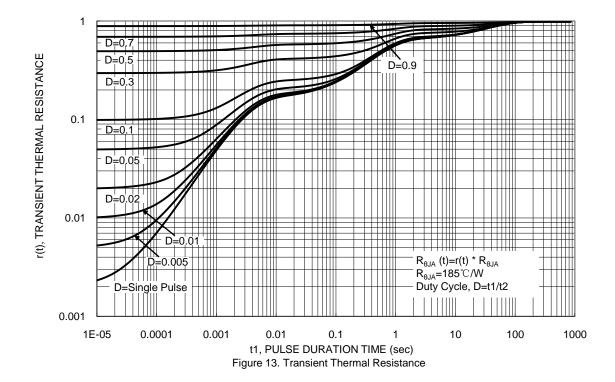




DMG2302UKQ Document number: DS40354 Rev. 2 - 2



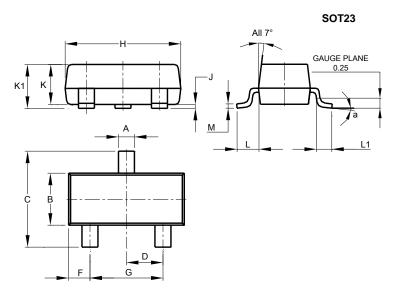






Package Outline Dimensions

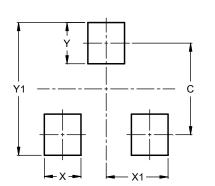
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
C	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
К	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	0°	8°							
All	All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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